Product data sheet

1. General description

P-channel enhancement mode Field-Effect Transistor (FET) in a leadless medium power DFN2020MD-6 (SOT1220) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Small and leadless ultra thin SMD plastic package: 2 x 2 x 0.65 mm
- Trench MOSFET technology
- Extended temperature range T_i = 175 °C
- · Side wettable flanks for optical solder inspection
- AEC-Q101 qualified

3. Applications

- · Relay driver
- · High-speed line driver
- · High-side load switch
- Switching circuits

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	-	-80	V
V_{GS}	gate-source voltage	T _j = 25 °C	[1]	-20	-	20	V
I _D	drain current	V _{GS} = -10 V; T _{sp} = 25 °C		-	-	-6	Α
P _{tot}	total power dissipation	T _{sp} = 25 °C		-	=	17	W
Static characte	eristics						
R _{DSon}	drain-source on-state resistance	$V_{GS} = -10 \text{ V}; I_D = -2 \text{ A}; T_j = 25 ^{\circ}\text{C}$		-	160	215	mΩ

[1] See application note AN90001.



5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	D	drain		
2	D	drain	157776	D
3	G	gate		
4	S	source	2 4 5	G (I⊨ ▼)
5	D	drain	3 8 4	
6	D	drain	Transparent top view	\$
7	D	drain	DFN2020MD-6 (SOT1220)	017aaa094
8	S	source		

6. Ordering information

Table 3. Ordering information

Type number Package						
	Name	Description	Version			
BUK6D215-80P		plastic, leadless thermal enhanced ultra thin small outline package with side-wettable flanks (SWF); 6 terminals; 0.65 mm pitch; 2 mm x 2 mm x 0.65 mm body	SOT1220			

7. Marking

Table 4. Marking codes

Type number	Marking code
BUK6D215-80P	NB

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	-80	V
V _{GS}	gate-source voltage	T _j = 25 °C	[1]	-20	20	V
I _D	drain current	V _{GS} = -10 V; T _{sp} = 25 °C		-	-6	Α
		V _{GS} = -10 V; T _{sp} = 100 °C		-	-4.2	Α
		V _{GS} = -10 V; T _{amb} = 25 °C		-	-2	Α
I _{DM}	peak drain current	T _{sp} = 25 °C; single pulse; t _p ≤ 10 μs		-	-24	Α
P _{tot}	total power dissipation	T _{sp} = 25 °C		-	17	W
		T _{amb} = 25 °C	[2]	-	2	W
Tj	junction temperature			-55	175	°C
T _{amb}	ambient temperature			-55	175	°C
T _{stg}	storage temperature			-65	175	°C
Source-drain d	liode				•	
Is	source current	T _{sp} = 25 °C		-	-6	Α
		T _{amb} = 25 °C	[2]	-	-1.8	Α
I _{SM}	peak source current	T _{sp} = 25 °C		-	-24	Α
Avalanche rug	gedness			'		
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	$T_{j(init)}$ = 25 °C; I_D = -1 A; DUT in avalanche (unclamped)		-	42	mJ

- [1] See application note AN90001.
- Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 6 cm².

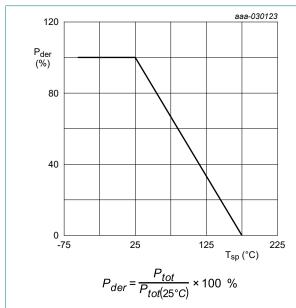
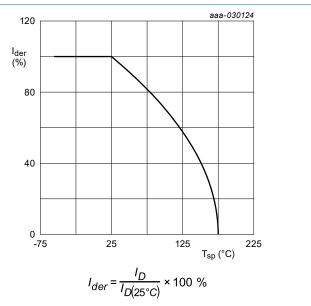


Fig. 1. Normalized total power dissipation as a function of solder point temperature



ig. 2. Normalized continuous drain current as a function of solder point temperature

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Nexperia BUK6D215-80P

80 V, P-channel Trench MOSFET

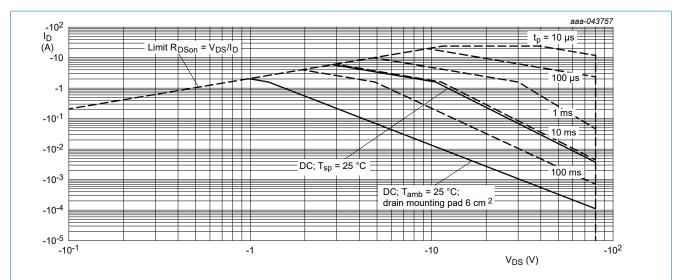


Fig. 3. Safe operating area; junction to ambient; continuous and peak drain currents as a function of drain-source voltage

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	65	75	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point			-	6	9	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 6 cm².

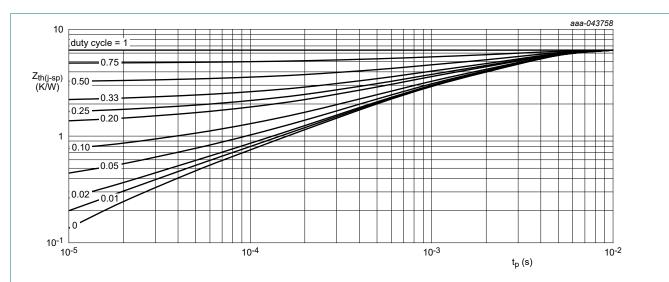


Fig. 4. Transient thermal impedance from junction to solder point as a function of pulse duration; typical values

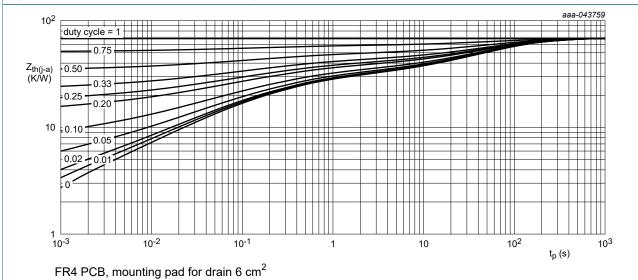


Fig. 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V _{(BR)DSS}	drain-source breakdown voltage	$I_D = -250 \mu A; V_{GS} = 0 V; T_j = 25 °C$	-80	-	-	V
V_{GSth}	gate-source threshold voltage	I_D = -250 μ A; V_{DS} = V_{GS} ; T_j = 25 °C	-1.4	-2	-2.7	V
I _{DSS}	drain leakage current	V _{DS} = -80 V; V _{GS} = 0 V; T _j = 25 °C	-	-	-1	μΑ
		V _{DS} = -80 V; V _{GS} = 0 V; T _j = 125 °C	-	-	-10	μΑ
I _{GSS} gate	gate leakage current	V _{GS} = -20 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-100	nA
		V _{GS} = 20 V; V _{DS} = 0 V; T _j = 25 °C	-	-	100	nA
R _{DSon}	drain-source on-state	V_{GS} = -10 V; I_D = -2 A; T_j = 25 °C	-	160	215	mΩ
	resistance	V _{GS} = -10 V; I _D = -2 A; T _j = 175 °C	-	360	480	mΩ
		V _{GS} = -4.5 V; I _D = -1.8 A; T _j = 25 °C	-	190	265	mΩ
9 _{fs}	forward transconductance	$V_{DS} = -5 \text{ V}; I_D = -2 \text{ A}; T_j = 25 \text{ °C}$	-	4.8	-	S
R_G	gate resistance	f = 1 MHz	-	10.5	-	Ω
Dynamic ch	aracteristics		'	'		
Q _{G(tot)}	total gate charge	V _{DS} = -40 V; I _D = -2 A; V _{GS} = -10 V;	-	10	15	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	1.7	-	nC
Q _{GD}	gate-drain charge		-	2.3	-	nC
C _{iss}	input capacitance	V _{DS} = -40 V; f = 1 MHz; V _{GS} = 0 V;	-	535	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	30	-	pF
C _{rss}	reverse transfer capacitance		-	19	-	pF
t _{d(on)}	turn-on delay time	$V_{DS} = -40 \text{ V}; I_D = -2 \text{ A}; V_{GS} = -10 \text{ V};$	-	3	-	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	4	-	ns
t _{d(off)}	turn-off delay time		-	22	-	ns
t _f	fall time]	-	26	-	ns
Source-drai	in diode		'			
V_{SD}	source-drain voltage	$I_S = -1.8 \text{ A}; V_{GS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}$	-	-0.7	-1.2	V
t _{rr}	reverse recovery time	I _S = -1.8 A; dI _S /dt = 100 A/μs;	-	19	-	ns
Q _r	recovered charge	$V_{GS} = 0 \text{ V}; V_{DS} = -40 \text{ V}; T_j = 25 \text{ °C}$	-	14	-	nC

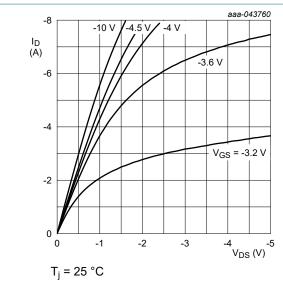


Fig. 6. Output characteristics: drain current as a function of drain-source voltage; typical values

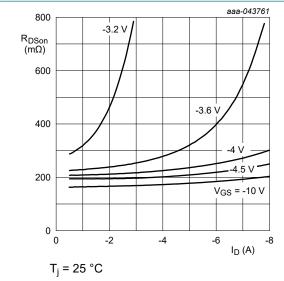


Fig. 8. Drain-source on-state resistance as a function of drain current; typical values

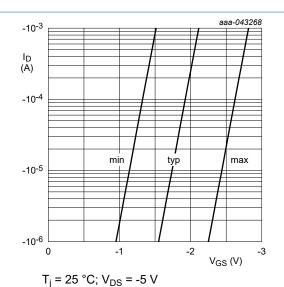


Fig. 7. Subthreshold drain current as a function of gate-source voltage

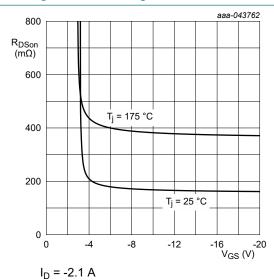


Fig. 9. Drain-source on-state resistance as a function of gate-source voltage; typical values

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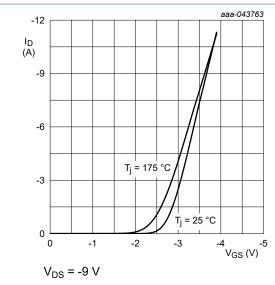


Fig. 10. Transfer characteristics: drain current as a function of gate-source voltage; typical values

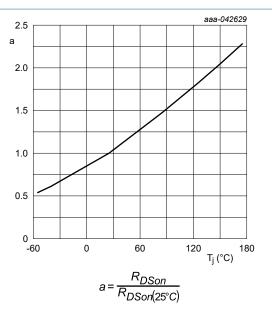


Fig. 11. Normalized drain-source on-state resistance as a function of junction temperature; typical values

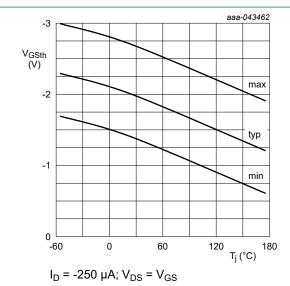


Fig. 12. Gate-source threshold voltage as a function of junction temperature

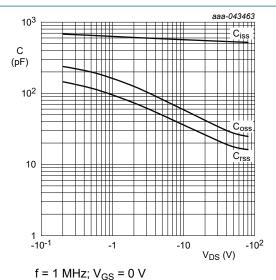


Fig. 13. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

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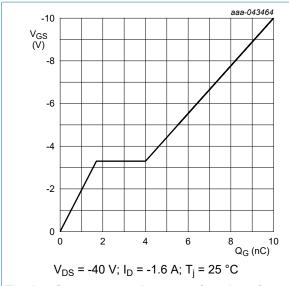


Fig. 14. Gate-source voltage as a function of gate charge; typical values

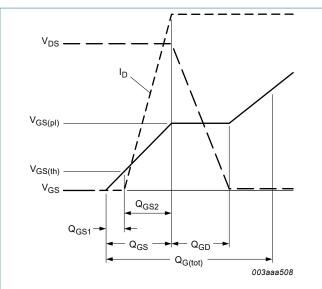


Fig. 15. Gate charge waveform definitions

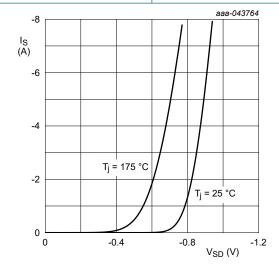
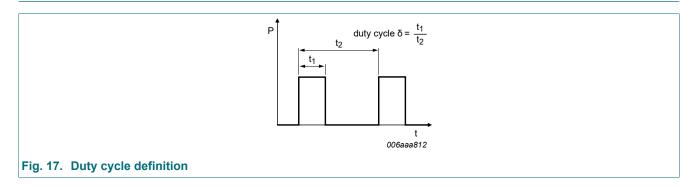


Fig. 16. Source current as a function of source-drain voltage; typical values

 $V_{GS} = 0 V$

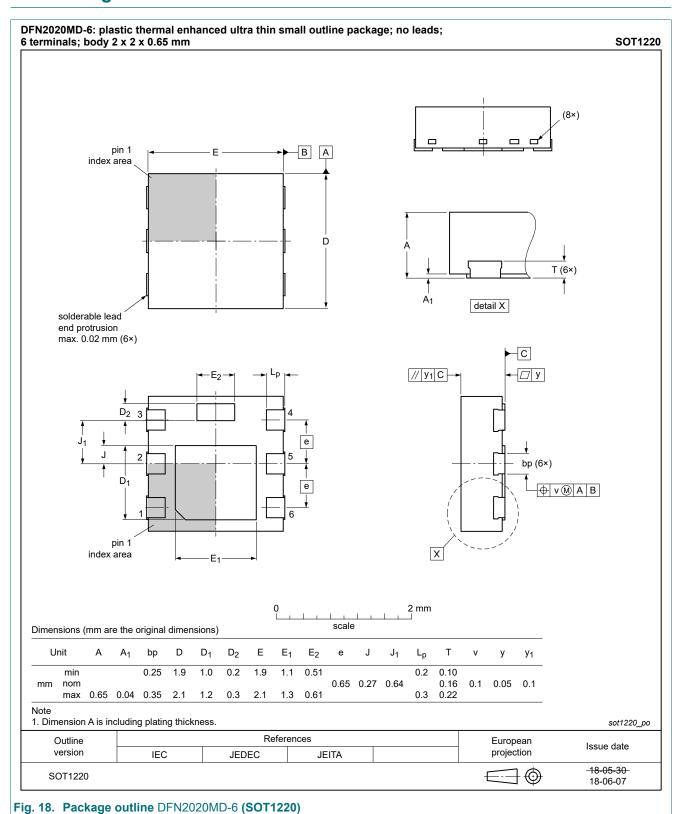
11. Test information



Quality information

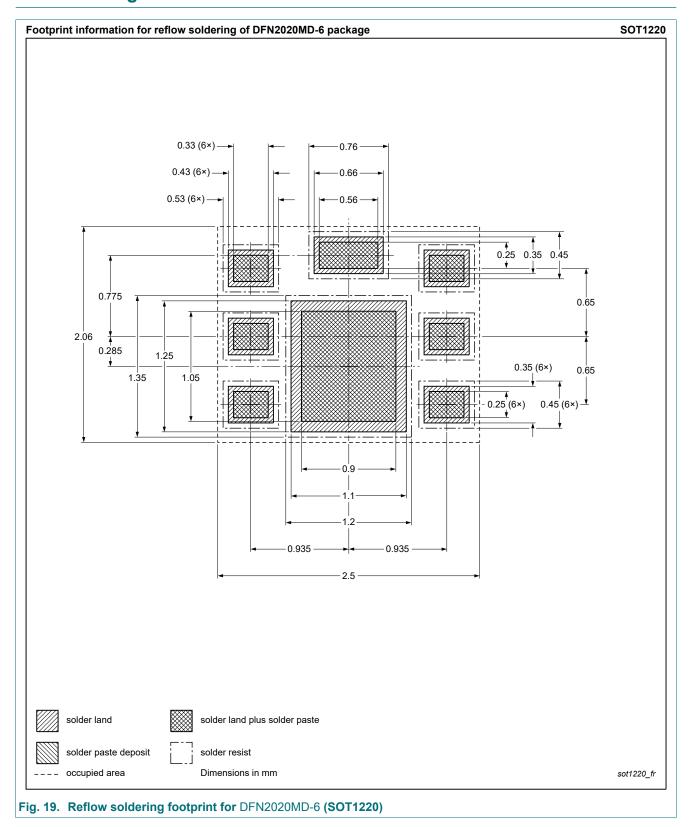
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

12. Package outline



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13. Soldering



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BUK6D215-80P

80 V, P-channel Trench MOSFET

14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
BUK6D215-80P v.1	20251001	Product data sheet	-	-

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
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